**AMC3301** 



# AMC3301 具有集成式直流/直流转换器的 ±250mV 输入、增强型隔离式 精密放大器

### 1 特性

• 3.3V 或 5V 单电源,具有集成直流/直流转换器

• ±250mV 输入电压范围,针对使用分流电阻器测量 电流进行了优化

固定增益:8.2 • 低直流误差:

- 失调电压:±150 µV(最大值)

- 温漂:±1μV/°C(最大值) - 增益误差:±0.2%(最大值)

- 增益误差漂移: ±40ppm/°C(最大值)

- 非线性度: ±0.04%(最大值)

高 CMTI: 85kV/µs(最小值)

系统级诊断功能

• 符合 CISPR-11 和 CISPR-25 EMI 标准

安全相关认证:

- 符合 DIN EN IEC 60747-17 (VDE 0884-17) 的 6000Vpk 增强型隔离

- 4250V<sub>RMS</sub> 隔离,符合 UL1577 标准且持续时长 为1分钟

• 可在更大的工业级温度范围内正常工作:-40°C至 +125°C

#### 2 应用

- 基于分流器的隔离式电流检测,用于:
  - 保护继电器
  - 电机驱动器
  - 电源
  - 光电逆变器

### 3 说明

AMC3301 是一款精密的隔离放大器,针对基于分流器 的电流测量进行了优化。完全集成的隔离式 DC/DC 转 换器允许从器件的低侧进行单电源操作,从而使该器件 成为空间受限应用的独特解决方案。增强型电容式隔离 栅已通过 DIN EN IEC 60747-17 (VDE 0884-17) 和 UL1577 认证,可支持高达 1.2kV<sub>RMS</sub> 的工作电压。

该隔离栅可将系统中以不同共模电压电平运行的各器件 隔开,并保护电压较低的器件免受高电压冲击。

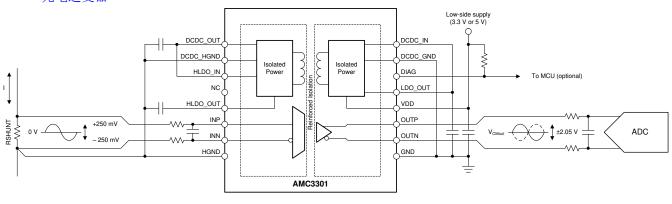
AMC3301 的输入经优化,可直接连接至低阻抗分流电 阻器或其他具有低信号电平的低阻抗电压源。出色的直 流精度和低温漂支持在 - 40°C 至 +125°C 的扩展工业 温度范围内进行精确的电流测量。

AMC3301 的集成直流/直流转换器故障检测和诊断输出 引脚可简化系统级设计和诊断。

#### 封装信息

	~1 ~ ~ I H · O·	
器件型号	封装 <sup>(1)</sup>	封装尺寸 <sup>(2)</sup>
AMC3301	DWE ( SOIC , 16 )	10.3mm × 10.3mm

- 如需更多信息,请参阅机械、封装和可订购信息。
- 封装尺寸(长×宽)为标称值,并包括引脚(如适用)。



典型应用



# **Table of Contents**

1 特性 1
2 应用
3 说明
4 Pin Configuration and Functions
5 Specifications4
5.1 Absolute Maximum Ratings4
5.2 ESD Ratings
5.3 Recommended Operating Conditions4
5.4 Thermal Information5
5.5 Power Ratings5
5.6 Insulation Specifications
5.7 Safety-Related Certifications
5.8 Safety Limiting Values7
5.9 Electrical Characteristics8
5.10 Switching Characteristics10
5.11 Timing Diagram10
5.12 Insulation Characteristics Curves11
5.13 Typical Characteristics12
6 Detailed Description18
6.1 Overview

6.2 Functional Block Diagram	18
6.3 Feature Description	18
6.4 Device Functional Modes	
7 Application and Implementation	
7.1 Application Information	
7.2 Typical Application	
7.3 Best Design Practices	
7.4 Power Supply Recommendations	
7.5 Layout	
8 Device and Documentation Support	
8.1 Device Support	
8.2 Documentation Support	
8.3 Receiving Notification of Documentation Updates.	
8.4 支持资源	
8.5 Trademarks	
8.6 静电放电警告	
8.7 术语表	
9 Revision History	
10 Mechanical, Packaging, and Orderable	51
	21
Information	o i



# **4 Pin Configuration and Functions**

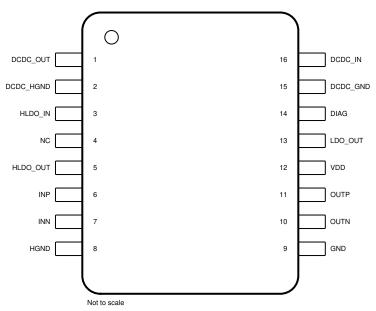


图 4-1. DWE Package, 16-Pin SOIC, Top View

表 4-1. Pin Functions

	PIN	TYPE	DESCRIPTION		
NO.	NAME	IIPE	DESCRIPTION		
1	DCDC_OUT	Power	High-side output of the isolated DC/DC converter; connect this pin to the HLDO_IN pin. <sup>(1)</sup>		
2	DCDC_HGND	High-side power ground	High-side ground reference for the isolated DC/DC converter; connect this pin to the HGND pin.		
3	HLDO_IN	Power	Input of the high-side LDO; connect this pin to the DCDC_OUT pin.(1)		
4	NC	_	No internal connection; connect this pin to HGND or leave this pin unconnected.		
5	HLDO_OUT	Power	Output of the high-side LDO. <sup>(1)</sup>		
6	INP	Analog input	Noninverting analog input. Either INP or INN must have a DC current path to HGND to define the common-mode input voltage. (2)		
7	INN	Analog input	Inverting analog input. Either INP or INN must have a DC current path to HGND to define the common-mode input voltage. (2)		
8	HGND	High-side signal ground	High-side analog ground; connect this pin to the DCDC_HGND pin.		
9	GND	Low-side signal ground	Low-side analog ground; connect this pin to the DCDC_GND pin.		
10	OUTN	Analog output	Inverting analog output.		
11	OUTP	Analog output	Noninverting analog output.		
12	VDD	Low-side power	Low-side power supply. <sup>(1)</sup>		
13	LDO_OUT	Power	Output of the low-side LDO; connect this pin to the DCDC_IN pin. The output of the LDO must not be loaded by external circuitry. <sup>(1)</sup>		
14	DIAG	Digital output	Active-low, open-drain status indicator output; connect this pin to the pullup supply (for example, VDD) using a resistor or leave this pin floating if not used.		
15	DCDC_GND	Low-side power ground	Low-side ground reference for the isolated DC/DC converter; connect this pin to the GND pin.		
16	DCDC_IN	Power	Low-side input of the isolated DC/DC converter; connect this pin to the LDO_OUT pin.(1)		

Product Folder Links: AMC3301

<sup>(1)</sup> See the *Power Supply Recommendations* section for power-supply decoupling recommendations.

<sup>(2)</sup> See the *Layout* section for details.

### 5 Specifications

### 5.1 Absolute Maximum Ratings

see (1)

		MIN	MAX	UNIT
Power-supply voltage	VDD to GND	- 0.3	6.5	V
Analog input voltage	INP, INN	HGND - 6	V <sub>HLDO_OUT</sub> + 0.5	V
Analog output voltage	OUTP, OUTN	GND - 0.5	VDD + 0.5	V
Digital output voltage	DIAG	GND - 0.5	6.5	V
Input current	Continuous, any pin except power-supply pins	- 10	10	mA
Temperature	Junction, T <sub>J</sub>		150	°C
Temperature	Storage, T <sub>stg</sub>	- 65	150	

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime

### 5.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
SUPPLY					
Low-side power supply	VDD to GND	3	3.3	5.5	V
INPUT					
Differential input voltage before clipping output	V <sub>IN</sub> = V <sub>INP</sub> - V <sub>INN</sub>		±320		mV
Specified linear differential full-scale voltage	V <sub>IN</sub> = V <sub>INP</sub> - V <sub>INN</sub>	- 250		250	mV
Absolute common-mode input voltage (1)	(V <sub>INP</sub> + V <sub>INN</sub> ) / 2 to HGND	- 2	V <sub>HLD</sub>	O_OUT	V
Operating common-mode input voltage	(V <sub>INP</sub> + V <sub>INN</sub> ) / 2 to HGND	- 0.16		1	V
OUTPUT					
Capacitive load	On OUTP or OUTN to GND2, Without any series resistance			500	pF
Capacitive load	OUTP to OUTN, Without any series resistance			250	pF
Resistive load	On OUTP or OUTN to GND2		10	1	kΩ
ОИТРИТ					
Pull-up supply-voltage for DIAG pin		0		VDD	V
ATURE RANGE					
Specified ambient temperature		- 40		125	°C
	Low-side power supply  INPUT  Differential input voltage before clipping output  Specified linear differential full-scale voltage  Absolute common-mode input voltage (1)  Operating common-mode input voltage  OUTPUT  Capacitive load  Resistive load  OUTPUT  Pull-up supply-voltage for DIAG pin  ATURE RANGE	Low-side power supply  INPUT  Differential input voltage before clipping output  Specified linear differential full-scale voltage  Absolute common-mode input voltage  Operating common-mode input voltage  Capacitive load  Capacitive load  Capacitive load  Resistive load  On OUTP or OUTN to GND2, Without any series resistance  Resistive load  On OUTP or OUTN to GND2  On OUTP or OUTN, Without any series resistance  On OUTP or OUTN to GND2  OUTPUT  Pull-up supply-voltage for DIAG pin  ATURE RANGE	Low-side power supply  Low-side power supply  Differential input voltage before clipping output  Specified linear differential full-scale voltage  Absolute common-mode input voltage (1)  Operating common-mode input voltage  (V <sub>INP</sub> + V <sub>INP</sub> ) / 2 to HGND - 2  Operating common-mode input voltage  (V <sub>INP</sub> + V <sub>INN</sub> ) / 2 to HGND - 0.16  OUTPUT  Capacitive load  On OUTP or OUTN to GND2, Without any series resistance  Capacitive load  Output outp	Low-side power supply   VDD to GND   3   3.3	Low-side power supply   VDD to GND   3 3.3 5.5

<sup>(1)</sup> Steady-state voltage supported by the device in case of a system failure. See specified common-mode input voltage V<sub>CM</sub> for normal operation. Observe analog input voltage range as specified in the Absolute Maximum Ratings table.

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### **5.4 Thermal Information**

		AMC3301	
	THERMAL METRIC <sup>(1)</sup>	DWE (SOIC)	UNIT
		16 PINS	
R <sub>0</sub> JA	Junction-to-ambient thermal resistance	73.5	°C/W
R <sub>θ JC(top)</sub>	Junction-to-case (top) thermal resistance	31	°C/W
R <sub>0</sub> JB	Junction-to-board thermal resistance	44	°C/W
ψ ЈТ	Junction-to-top characterization parameter	16.7	°C/W
ψ ЈВ	Junction-to-board characterization parameter	42.8	°C/W
R <sub>θ JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

# 5.5 Power Ratings

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P <sub>D</sub>	Maximum power dissipation	VDD = 5.5 V			231	mW
		VDD = 3.6 V		-	151	11144

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### **5.6 Insulation Specifications**

over operating ambient temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	VALUE	UNIT
GENERA	AL			
CLR	External clearance (1)	Shortest pin-to-pin distance through air	≥ 8	mm
CPG	External creepage (1)	Shortest pin-to-pin distance across the package surface	≥ 8	mm
	Distance through the insulation	Minimum internal gap (internal clearance - capacitive signal isolation)	≥ 21	
DTI		Minimum internal gap (internal clearance - transformer power isolation)	≥ 120	— μm
СТІ	Comparative tracking index	DIN EN 60112 (VDE 0303-11); IEC 60112	≥ 600	V
	Material group	According to IEC 60664-1	I	
	Overvoltage category	Rated mains voltage ≤ 600 V <sub>RMS</sub>	1-111	
	per IEC 60664-1	Rated mains voltage ≤ 1000 V <sub>RMS</sub>	I-II	
DIN EN I	EC 60747-17 (VDE 0884-17) <sup>(2)</sup>	1		
V <sub>IORM</sub>	Maximum repetitive peak isolation voltage	At AC voltage	1700	V <sub>PK</sub>
\/	Maximum-rated isolation	At AC voltage (sine wave)	1200	V <sub>RMS</sub>
V <sub>IOWM</sub>	working voltage	At DC voltage	1700	$V_{DC}$
V <sub>IOTM</sub>	Maximum transient isolation voltage	V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60s (qualification test), V <sub>TEST</sub> = 1.2 × V <sub>IOTM</sub> , t = 1s (100% production test)	6000	V <sub>PK</sub>
V <sub>IMP</sub>	Maximum impulse voltage <sup>(3)</sup>	Tested in air, 1.2/50µs waveform per IEC 62368-1	7700	$V_{PK}$
V <sub>IOSM</sub>	Maximum surge isolation voltage <sup>(4)</sup>	Tested in oil (qualification test), 1.2/50µs waveform per IEC 62368-1	10000	V <sub>PK</sub>
	Apparent charge <sup>(5)</sup>	Method a, after input/output safety test subgroups 2 and 3, $V_{pd(ini)} = V_{IOTM}, t_{ini} = 60s, V_{pd(m)} = 1.2 \times V_{IORM}, t_{m} = 10s$	≤ 5	
		Method a, after environmental tests subgroup 1, $V_{pd(ini)} = V_{IOTM}, t_{ini} = 60s, V_{pd(m)} = 1.6 \times V_{IORM}, t_{m} = 10 s$	≤ 5	pC
q <sub>pd</sub>		Method b1, at preconditioning (type test) and routine test, $V_{pd(ini)} = 1.2 \times V_{IOTM}, t_{ini} = 1s, V_{pd(m)} = 1.875 \times V_{IORM}, t_m = 1s$	≤ 5	
		Method b2, at routine test (100% production) <sup>(7)</sup> , $V_{pd(ini)} = V_{pd(m)} = 1.2 \times V_{IOTM}, t_{ini} = t_m = 1s$	≤ 5	pC
C <sub>IO</sub>	Barrier capacitance, input to output <sup>(6)</sup>	V <sub>IO</sub> = 0.5 V <sub>PP</sub> at 1MHz	<b>≅</b> 4.5	pF
		V <sub>IO</sub> = 500 V at T <sub>A</sub> = 25°C	> 10 <sup>12</sup>	
R <sub>IO</sub>	Insulation resistance, input to output <sup>(6)</sup>	$V_{IO}$ = 500 V at 100°C $\leqslant$ T <sub>A</sub> $\leqslant$ 125°C	> 10 <sup>11</sup>	Ω
		V <sub>IO</sub> = 500 V at T <sub>S</sub> = 150°C	> 10 <sup>9</sup>	
	Pollution degree		2	
	Climatic category		40/125/21	
UL1577				
V <sub>ISO</sub>	Withstand isolation voltage	$V_{TEST} = V_{ISO}$ , t = 60 s (qualification test), $V_{TEST} = 1.2 \times V_{ISO}$ , t = 1 s (100% production test)	4250	V <sub>RMS</sub>

- (1) Apply creepage and clearance requirements according to the specific equipment isolation standards of an application. Care must be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board (PCB) do not reduce this distance. Creepage and clearance on a PCB become equal in certain cases. Techniques such as inserting grooves, ribs, or both on a PCB are used to help increase these specifications.
- (2) This coupler is suitable for *safe electrical insulation* only within the safety ratings. Compliance with the safety ratings must be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air to determine the surge immunity of the package.
- (4) Testing is carried in oil to determine the intrinsic surge immunity of the isolation barrier.
- (5) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (6) All pins on each side of the barrier are tied together, creating a two-pin device.
- (7) Either method b1 or b2 is used in production.

### 5.7 Safety-Related Certifications

VDE	UL
DIN EN IEC 60747-17 (VDE 0884-17), EN IEC 60747-17, DIN EN IEC 62368-1 (VDE 0868-1), EN IEC 62368-1, IEC 62368-1 Clause : 5.4.3 ; 5.4.4.4 ; 5.4.9	Recognized under 1577 component recognition and CSA component acceptance NO 5 programs
Reinforced insulation	Single protection
Certificate number: 40040142	File number: E181974

### 5.8 Safety Limiting Values

Safety limiting <sup>(1)</sup> intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure ofthe I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Is	Safety input, output, or supply current	R <sub>0</sub> JA = 73.5°C/W, VDD = 5.5 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C			309	mA
		R <sub>0</sub> JA = 73.5°C/W, VDD = 3.6 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C			472	MA
Ps	Safety input, output, or total power	R <sub>θ JA</sub> = 73.5°C/W, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C			1700	mW
T <sub>S</sub>	Maximum safety temperature				150	°C

(1) The maximum safety temperature, T<sub>S</sub>, has the same value as the maximum junction temperature, T<sub>J</sub>, specified for the device. The I<sub>S</sub> and P<sub>S</sub> parameters represent the safety current and safety power, respectively. Do not exceed the maximum limits of I<sub>S</sub> and P<sub>S</sub>. These limits vary with the ambient temperature, T<sub>A</sub>.

The junction-to-air thermal resistance,  $R_{\theta JA}$ , in the *Thermal Information* table is that of a device installed on a high-K test board for leaded surface-mount packages. Use these equations to calculate the value for each parameter:

Product Folder Links: AMC3301

 $T_J = T_A + R_{\theta JA} \times P$ , where P is the power dissipated in the device.

 $T_{J(max)} = T_S = T_A + R_{\theta JA} \times P_S$ , where  $T_{J(max)}$  is the maximum junction temperature.

 $P_S = I_S \times VDD_{max}$ , where  $VDD_{max}$  is the maximum low-side voltage.



### **5.9 Electrical Characteristics**

minimum and maximum specifications apply from  $T_A = -40^{\circ}\text{C}$  to +125°C, VDD = 3.0 V to 5.5 V, INP = -250 mV, INN = HGND = 0 V, and the external components listed in the *Typical Application* section; typical specifications are at  $T_A = 25^{\circ}\text{C}$ , and VDD = 3.3 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ANALOG	INPUT					
R <sub>IN</sub>	Single-ended input resistance	INN = HGND		19		k O
R <sub>IND</sub>	Differential input resistance			22		kΩ
I <sub>IB</sub>	Input bias current	INP = INN = HGND; I <sub>IB</sub> = (I <sub>IBP</sub> + I <sub>IBN</sub> ) / 2	- 41	- 30	- 24	μΑ
TCI <sub>IB</sub>	Input bias current drift			0.8		nA/°C
I <sub>IO</sub>	Input offset current	$I_{IO} =  I_{IBP} - I_{IBN} $		1.4		nA
C <sub>IN</sub>	Single-ended input capacitance	INN = HGND, f <sub>IN</sub> = 275 kHz		2		F
C <sub>IND</sub>	Differential input capacitance	f <sub>IN</sub> = 275 kHz		1		pF
ANALOG	ОИТРИТ				'	
	Nominal gain			8.2		V/V
V <sub>CMout</sub>	Common-mode output voltage		1.39	1.44	1.49	V
V <sub>CLIPout</sub>	Clipping differential output voltage	$V_{OUT} = (V_{OUTP} - V_{OUTN});$ $ V_{IN}  =  V_{INP} - V_{INN}  > V_{Clipping}$		±2.49		V
V <sub>Failsafe</sub>	Failsafe differential output voltage	$V_{OUT}$ = $(V_{OUTP} - V_{OUTN})$ ; $V_{DCDC\_OUT} \le V_{DCDCUV}$ , or $V_{HLDO\_OUT} \le V_{HLDOUV}$	-	- 2.57	-2.5	V
BW	Output bandwidth		290	334		kHz
R <sub>OUT</sub>	Output resistance	On OUTP or OUTN		0.2		Ω
	Output short-circuit current	On OUTP or OUTN, sourcing or sinking, INP = INN = HGND, outputs shorted to either GND or VDD		14		mA
CMTI	Common-mode transient immunity	HGND - GND  = 2 kV	85	135		kV/μs
ACCURA	CY					
V <sub>OS</sub>	Input offset voltage(1) (2)	T <sub>A</sub> = 25°C, INP = INN = HGND	- 0.15	±0.02	0.15	mV
TCV <sub>OS</sub>	Input offset drift <sup>(1)</sup> (2) (4)		- 1	±0.15	1	uV/°C
E <sub>G</sub>	Gain error <sup>(1)</sup>	T <sub>A</sub> = 25°C	- 0.2%	±0.04%	0.2%	
TCE <sub>G</sub>	Gain error drift <sup>(1)</sup> (5)		- 40	±6	40	ppm/°C
	Nonlinearity <sup>(1)</sup>		- 0.04%	±0.002%	0.04%	
	Nonlinearity drift <sup>(1)</sup>			0.9		ppm/°C
OND	Character and	V <sub>IN</sub> = 0.5 V <sub>PP</sub> , f <sub>IN</sub> = 1 kHz, BW = 10 kHz, 10 kHz filter	80	85		.ID
SNR	Signal-to-noise ratio	$V_{IN}$ = 0.5 $V_{PP}$ , $f_{IN}$ = 10 kHz, BW = 100 kHz, 1 MHz filter	67	71		dB
THD	Total harmonic distortion <sup>(3)</sup>	V <sub>IN</sub> = 0.5 Vpp, f <sub>IN</sub> = 10 kHz, BW = 100 kHz		- 85		dB
	Output noise	INP = INN = HGND, f <sub>IN</sub> = 0 Hz, BW = 100 kHz		300		$\mu V_{RMS}$
CMRR	Common mode rejection ratio	$f_{IN}$ = 0 Hz, $V_{CM \; min} \leqslant V_{CM} \leqslant V_{CM}$ max		- 97		dB
CIVICK	Common-mode rejection ratio	$f_{\text{IN}}$ = 10 kHz, $V_{\text{CM min}} \leqslant V_{\text{CM}} \leqslant V_{\text{CM}}$		- 98		

Product Folder Links: AMC3301

## 5.9 Electrical Characteristics (续)

minimum and maximum specifications apply from  $T_A = -40^{\circ}\text{C}$  to +125°C, VDD = 3.0 V to 5.5 V, INP = -250 mV to +250 mV, INN = HGND = 0 V, and the external components listed in the *Typical Application* section; typical specifications are at  $T_A = 25^{\circ}\text{C}$ , and VDD = 3.3 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		VDD from 3.0 V to 5.5 V, at dc, input referred		- 109		
PSRR	Power-supply rejection ratio	INP = INN = HGND, VDD from 3.0 V to 5.5 V, 10 kHz / 100 mV ripple, input referred		- 98		dB
DIGITAL O	JTPUT (DIAG)				1	
V <sub>OL</sub>	Low-level output voltage	I <sub>SINK</sub> = 4 mA		80	250	mV
I <sub>LKG</sub>	Open-drain output leakage current	VDD = 5V		5	100	nA
POWER SU	PPLY				'	
IDD Low-side supply current		no external load on HLDO		27.5	40	mA
טטו	Low-side supply current	1 mA external load on HLDO		29.5	42	ША
VDD	VDD analog undervoltage detection	VDD rising			2.9	V
VDD <sub>UV</sub>	threshold	VDD falling			2.8	V
VDD	VDD digital report throughold	VDD rising			2.5	V
VDD <sub>POR</sub>	VDD digital reset threshold	VDD falling			2.4	V
V <sub>DCDC_OUT</sub>	DCDC output voltage	DCDC_OUT to HGND	3.1	3.5	4.65	V
V <sub>DCDCUV</sub>	DCDC output undervoltage detection threshold voltage	DCDC output falling	2.1	2.25		V
V <sub>HLDO_OUT</sub>	High-side LDO output voltage	HLDO to HGND, 4 mA external load, VDD > 3.6 V	3	3.2	3.4	V
V <sub>HLDOUV</sub>	High-side LDO output undervoltage detection threshold voltage	HLDO output falling	2.4	2.6		V
1	High-side supply current for auxiliary	3 V ≤ VDD < 3.6 V, load connected from HLDO_OUT to HGND, non-switching			1	mA
I <sub>H</sub>	circuitry	3.6 V ≤ VDD ≤ 5.5 V, load connected from HLDO_OUT to HGND, non-switching			4.0	mA
t <sub>AS</sub>	Analog settling time	VDD step to 3.0 V, to OUTP and OUTN valid, 0.1% settling		0.9	1.4	ms

- (1) The typical value includes one standard deviation ("sigma") at nominal operating conditions.
- (2) This parameter is input referred.
- (3) THD is the ratio of the rms sum of the amplitues of first five higher harmonics to the amplitude of the fundamental.
- (4) Offset error temperature drift is calculated using the box method, as described by the following equation:  $TCV_{OS} = (V_{OS,MAX} V_{OS,MIN}) / TempRange$  where  $V_{OS,MAX}$  and  $V_{OS,MIN}$  refer to the maximum and minimum  $V_{OS}$  values measured within the temperature range ( 40 to 125°C).
- (5) Gain error temperature drift is calculated using the box method, as described by the following equation:  $TCE_G(ppm) = ((E_{G,MAX} E_{G,MIN}) / TempRange) \times 10^4 \text{ where } E_{G,MAX} \text{ and } E_{G,MIN} \text{ refer to the maximum and minimum } E_G \text{ values (in %)}$  measured within the temperature range ( 40 to 125°C).

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9



### **5.10 Switching Characteristics**

over operating ambient temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>r</sub>	Output signal rise time			1.3		μs
t <sub>f</sub>	Output signal fall time			1.3		μs
	V <sub>INx</sub> to V <sub>OUTx</sub> signal delay (50% - 10%)	Unfiltered output		1	1.5	μs
	V <sub>INx</sub> to V <sub>OUTx</sub> signal delay (50% - 50%)	Unfiltered output		1.6	2.1	μs
	V <sub>INx</sub> to V <sub>OUTx</sub> signal delay (50% - 90%)	Unfiltered output		2.5	3	μs

# **5.11 Timing Diagram**

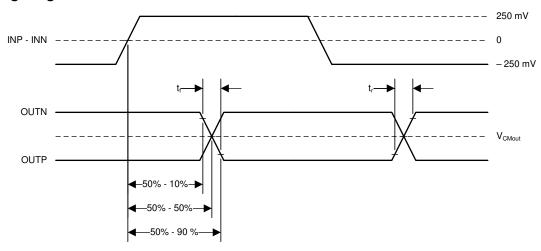
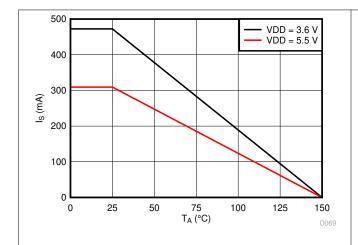


图 5-1. Rise, Fall, and Delay Time Waveforms

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### **5.12 Insulation Characteristics Curves**



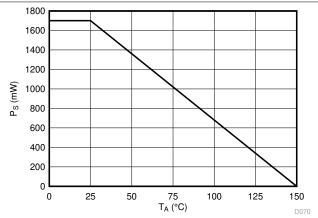
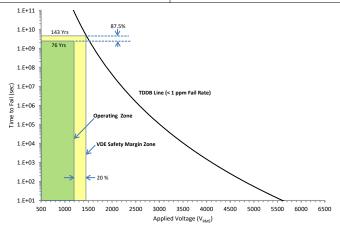


图 5-2. Thermal Derating Curve for Safety-Limiting Current per VDE

图 5-3. Thermal Derating Curve for Safety-Limiting Power per VDE



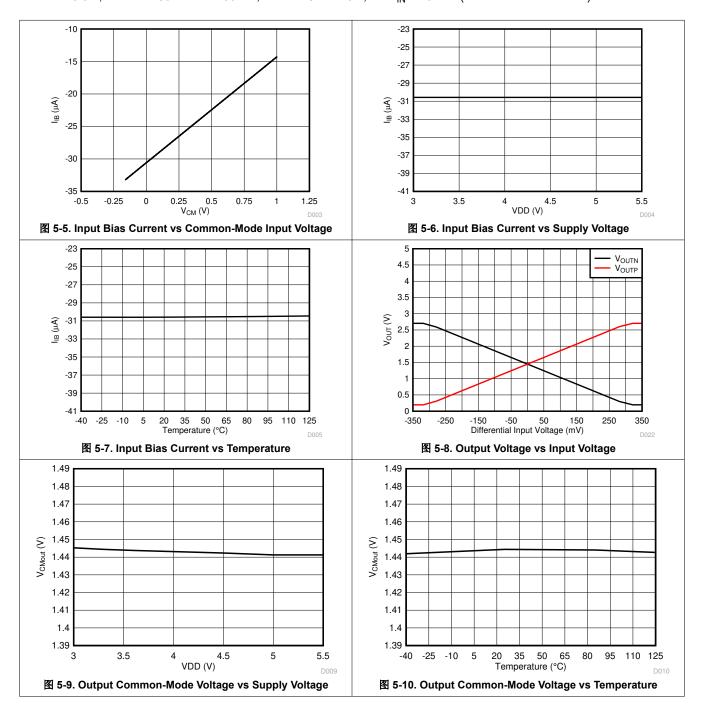
 $T_A$  up to 150°C, stress-voltage frequency = 60 Hz, isolation working voltage = 1200  $V_{RMS}$ , operating lifetime = 76 years

图 5-4. Reinforced Isolation Capacitor Lifetime Projection

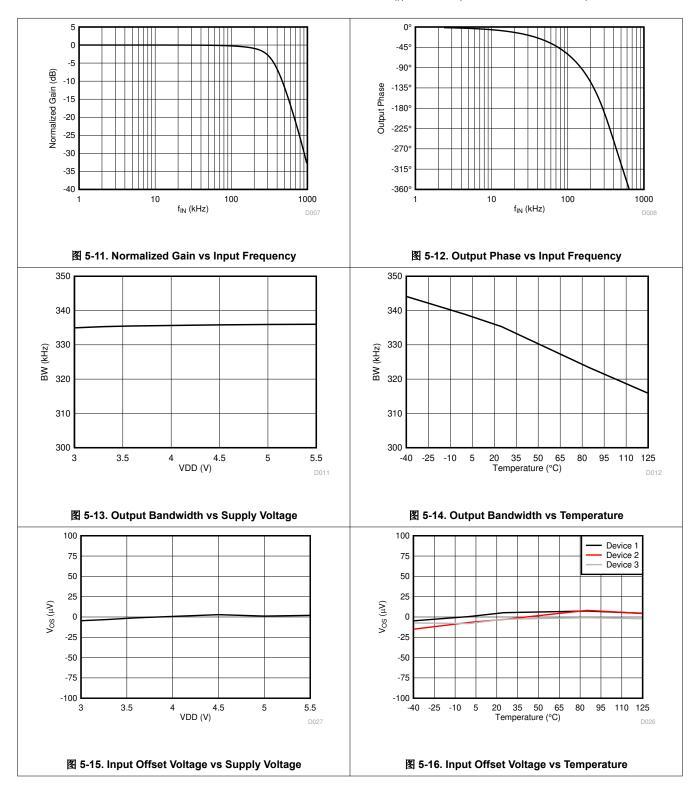


### **5.13 Typical Characteristics**

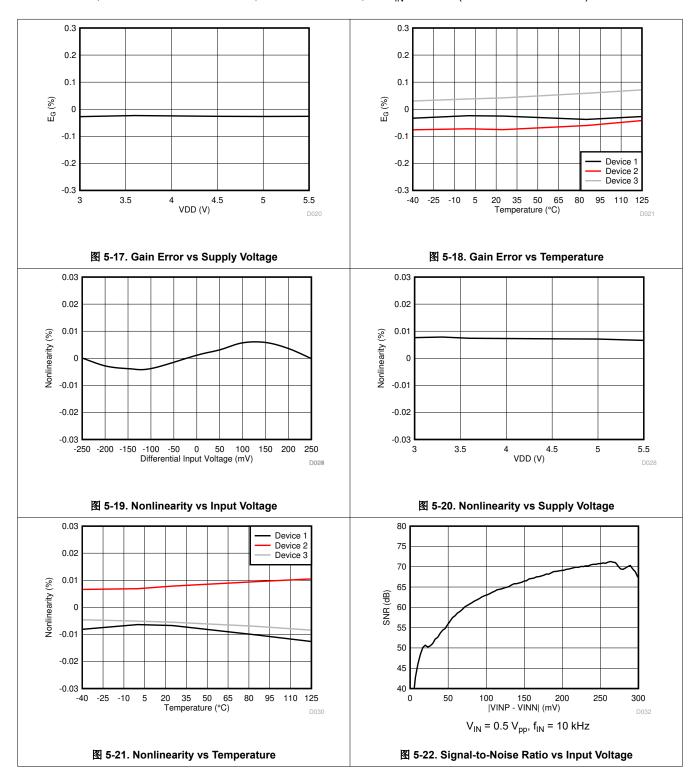
at VDD = 3.3 V, INP = -250 mV to +250 mV, INN = HGND = 0 V, and  $f_{IN}$  = 10 kHz (unless otherwise noted)

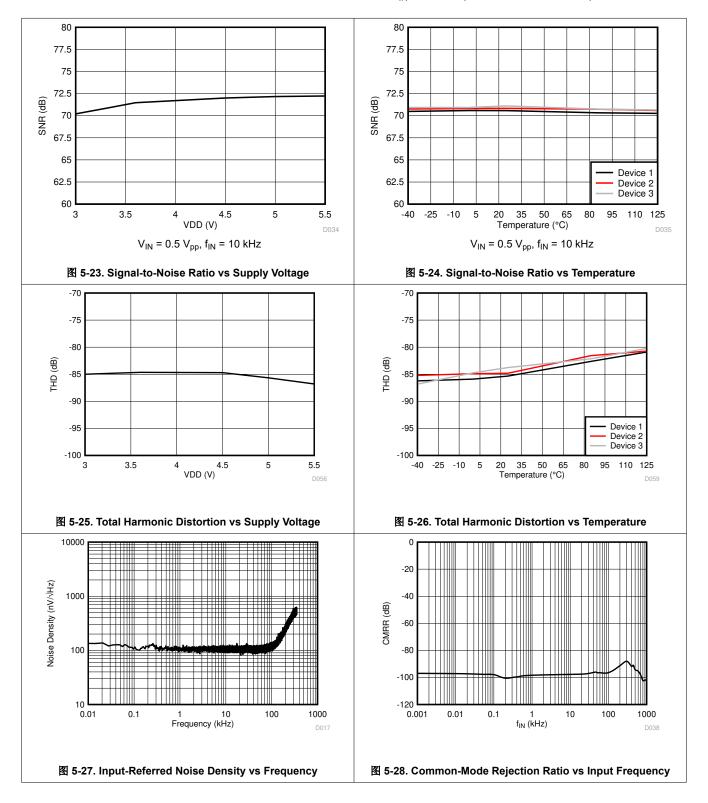


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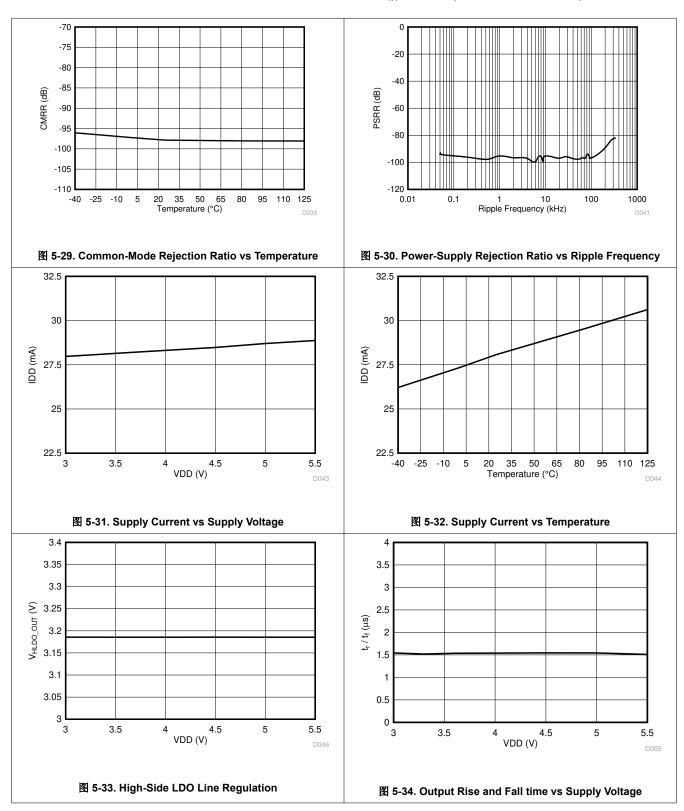




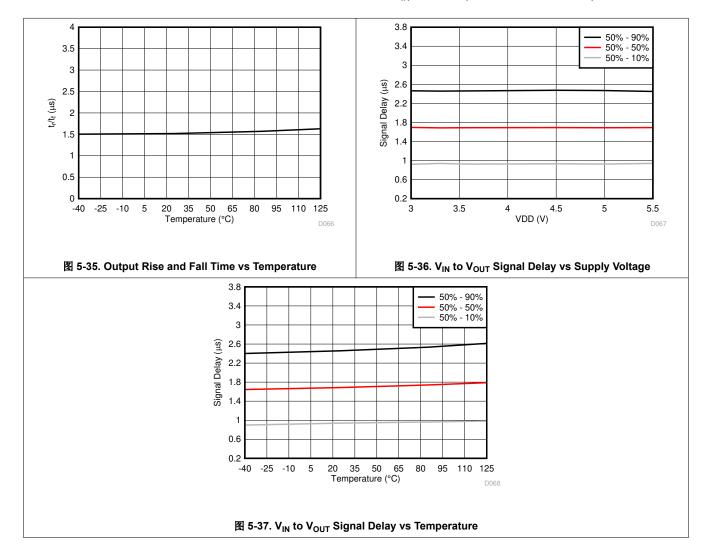








at VDD = 3.3 V, INP = -250 mV to +250 mV, INN = HGND = 0 V, and  $f_{IN}$  = 10 kHz (unless otherwise noted)



Product Folder Links: AMC3301

17

English Data Sheet: SBAS917



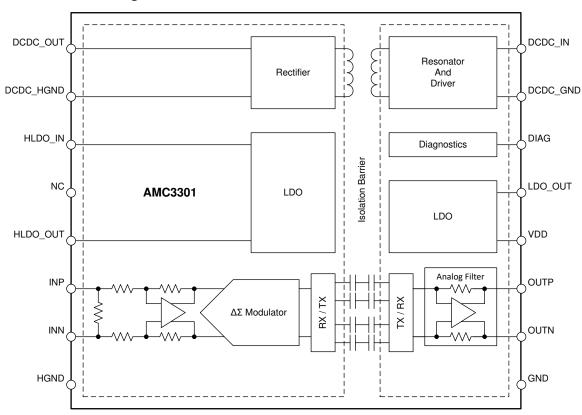
### **6 Detailed Description**

#### 6.1 Overview

The AMC3301 is a fully differential, precision, isolated amplifier with a fully integrated DC/DC converter that can supply the device from a single 3.3-V or 5-V voltage supply on the low-side. The input stage of the device consists of a fully differential amplifier that drives a second-order, delta-sigma ( $\Delta \Sigma$ ) modulator. The modulator uses an internal voltage reference and clock generator to convert the analog input signal to a digital bitstream. The drivers (termed TX in the  $Functional\ Block\ Diagram$ ) transfer the output of the modulator across the isolation barrier that separates the high-side and low-side voltage domains. As shown in the  $Functional\ Block\ Diagram$ , the received bitstream and clock are synchronized and processed by a fourth-order analog filter on the low-side and presented as a differential output of the device

The signal path is isolated by a double capacitive silicon dioxide (SiO<sub>2</sub>) insuation barrier, whereas power isolation uses an on-chip transformer separated by a thin-film polymer as the insulating material.

### 6.2 Functional Block Diagram



#### **6.3 Feature Description**

#### 6.3.1 Analog Input

The differential amplifier input stage of the AMC3301 feeds a second-order, switched-capacitor, feed-forward  $\Delta \Sigma$  modulator. The gain of the differential amplifier is set by internal precision resistors with a differential input impedance of R<sub>IND</sub>. The modulator converts the analog signal into a bitstream that is transferred across the isolation barrier, as described in the *Data Isolation Channel Signal Transmission* section.

There are two restrictions on the analog input signals (INP and INN). First, if the input voltages V<sub>INP</sub> or V<sub>INN</sub> exceed the range specified in the *Absolute Maximum Ratings* table, the input current must be limited to the absolute maximum value, because the device input electrostatic discharge (ESD) diodes turns on. In addition, the linearity and parametric performance of the device are ensured only when the analog input voltage remains

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within linear full-scale range ( $V_{\text{FSR}}$ ) and within the common-mode input voltage range ( $V_{\text{CM}}$ ) as specified in the *Recommended Operating Conditions* table.

19

Product Folder Links: AMC3301

#### 6.3.2 Data Isolation Channel Signal Transmission

The AMC3301 uses an on-off keying (OOK) modulation scheme, as shown in 🗟 6-1, to transmit the modulator output bitstream across the capacitive SiO<sub>2</sub>-based isolation barrier. The transmit driver (TX) shown in the *Functional Block Diagram* transmits an internally generated, high-frequency carrier across the isolation barrier to represent a digital *one* and does not send a signal to represent a digital *zero*. The nominal frequency of the carrier used inside the AMC3301 is 480 MHz.

The receiver (RX) on the other side of the isolation barrier recovers and demodulates the signal and produces the output. The AMC3301 transmission channel is optimized to achieve the highest level of common-mode transient immunity (CMTI) and lowest level of radiated emissions caused by the high-frequency carrier and RX/TX buffer switching.

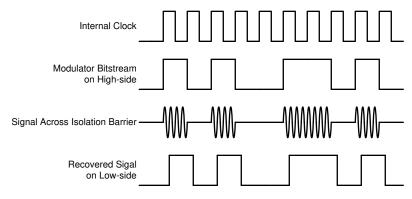


图 6-1. OOK-Based Modulation Scheme

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#### 6.3.3 Analog Output

The AMC3301 offers a differential analog output comprised of the OUTP and OUTN pins. For differential input voltages (V<sub>INP</sub> - V<sub>INN</sub>) in the range from - 250 mV to +250 mV, the device provides a linear response with a nominal gain of 8.2. For example, for a differential input voltage of 250 mV, the differential output voltage (VOLTE V<sub>OLITN</sub>) is 2.05 V. At zero input (INP shorted to INN), both pins output the same common-mode output voltage V<sub>CMout</sub>, as specified in the *Electrical Characteristics* table. For absolute differential input voltages greater than 250 mV but less than 320 mV, the differential output voltage continues to increase in magnitude but with reduced linearity performance. The outputs saturate at a differential output voltage of V<sub>CI IPout</sub> as shown in 图 6-2 if the differential input voltage exceeds the V<sub>Clipping</sub> value.

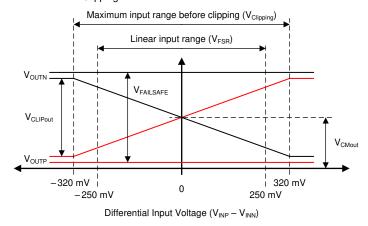


图 6-2. Output Behavior of the AMC3301

The AMC3301 provides a fail-safe output that simplifies diagnostics on system level. 

8 6-2 shows the fail-safe mode, in which the AMC3301 outputs a negative differential output voltage that does not occur under normal operating conditions. The fail-safe output is active in two cases:

- The low-side does not receive data from the high-side (for example, because of a loss of power on the high side).
- The high-side DC/DC output voltage (DCDC OUT) or the high-side LDO output voltage (HLDO OUT) drop below their respective undervoltage detection thresholds (brown-out).

Use the maximum V<sub>FAILSAFE</sub> voltage specified in the *Electrical Characteristics* table as a reference value for the fail-safe detection on the system level.

Product Folder Links: AMC3301

21



#### 6.3.4 Isolated DC/DC Converter

The AMC3301 offers a fully integrated isolated DC/DC converter that includes the following components as illustrated in the Functional Block Diagram:

- Low-dropout regulator (LDO) on the low-side to stabilize the supply voltage VDD that drives the low-side of the converter. This circuit does not output a constant voltage and is not intended for driving any external load.
- Low-side full-bridge inverter and drivers
- Laminate-based, air-core transformer for high-immunity to magnetic fields
- High-side full-bridge rectifier
- High-side LDO to stabilize the output voltage of the DC/DC converter for high analog performance of the signal path. The high-side LDO outputs a constant voltage and can provide a limited amount of current to power external circuitry.

The DC/DC converter uses a spread-spectrum clock generation technique to reduce the spectral density of the electromagnetic radiation. The resonator frequency is synchronized to the operation of the  $\Delta \Sigma$  modulator to minimize the interference with data transmission and support the high analog performance of the device.

The architecture of the DC/DC converter is optimized to drive the high-side circuitry of the AMC3301 and can source up to I<sub>H</sub> of additional DC current for an optional auxiliary circuit such as an active filter, preamplifier, or comparator. I<sub>H</sub> is specified in the *Electrical Characteristics* table as a DC, non-switching current.

#### 6.3.5 Diagnostic Output

The open-drain DIAG pin can be monitored to confirm the device is operational and the output voltage is valid. As shown in 8 6-3, during power-up, the DIAG pin is actively held low until the high-side supply is in regulation and the device operates properly. During normal operation, the DIAG pin is in high-impedance (Hi-Z) state and is pulled high through an external pullup resistor. The DIAG pin is actively pulled low if:

- The low-side does not receive data from the high-side (for example, because of a loss of power on the high side). In this case, the amplifier outputs are driven to the V<sub>FAII SAFF</sub> value that is shown in 🗵 6-2.
- The high-side DC/DC output voltage (DCDC OUT) or the high-side LDO output voltage (HLDO OUT) drop below their respective undervoltage detection thresholds (brown-out). In this case, the low-side may still receive data from the high-side but the data may not be valid. The amplifier outputs are driven to the V<sub>FAILSAFE</sub> value that is shown in 图 6-2.



图 6-3. DIAG Output Under Different Operating Conditions

During normal operation, the DIAG pin is in a high-impedance state. Connect the DIAG pin to a pullup resistor or leave open if not used.

#### 6.4 Device Functional Modes

The AMC3301 is operational when the power supply VDD is applied, as specified in the Recommended Operating Conditions table.

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## 7 Application and Implementation

#### 备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 7.1 Application Information

The low input voltage range, low nonlinearity, and low temperature drift make the AMC3301 a high-performance solution for industrial applications where shunt-based current sensing with high common-mode voltage levels is required.

### 7.2 Typical Application

The AMC3301 is ideally suited for shunt-based current sensing applications where accurate current monitoring is required in the presence of high common-mode voltages. The AMC3301 integrates an isolated power supply for the high-voltage side and therefore makes the device particularly easy to use in applications that do not have a high-side supply readily available or where a high-side supply is referenced to a different ground potential than the signal to be measured.

₹ 7-1 shows a simplified schematic of the AMC3301 in a solar inverter where the phase current is measured on the grid-side of an LCL filter. Although the system offers a supply for the high-side gate driver, there is a large common-mode voltage between the gate driver supply ground reference and the shunt resistor on the other side of the LCL filter. Therefore, the gate driver supply is not suitable for powering the high-side of an isolated amplifier that measures the voltage across the shunt. The integrated isolated power supply of the AMC3301 solves that problem and enables current sensing at locations that is optimal for the system.

Product Folder Links: AMC3301

The diagram also shows the AMC3330 being used for sensing the AC output voltage.

23

English Data Sheet: SBAS917



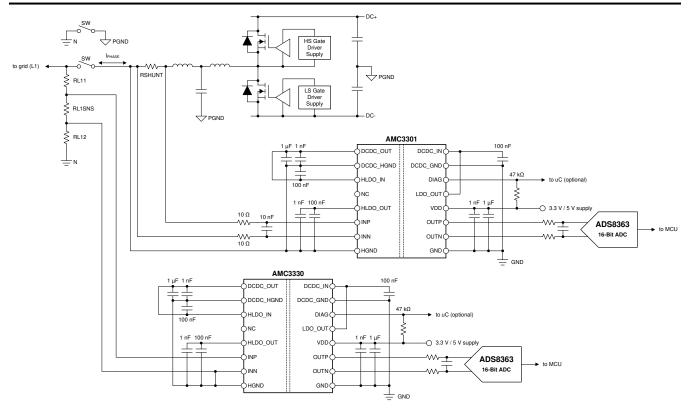


图 7-1. The AMC3301 in a Solar Inverter Application

English Data Sheet: SBAS917

#### 7.2.1 Design Requirements

表 7-1 lists the parameters for this typical application.

表	7-1.	Design	Requirements

PARAMETER	VALUE
Supply voltage	3.3 V or 5 V
Voltage drop across the shunt for a linear response (V <sub>SHUNT</sub> )	±250 mV (maximum)

#### 7.2.2 Detailed Design Procedure

The AMC3301 requires a single 3.3-V or 5-V supply on its low-side. The high-side supply is internally generated by an integrated DC/DC converter as explained in the Isolated DC/DC Converter section.

The ground reference (HGND) is derived from the terminal of the shunt resistor that is connected to the negative input of the AMC3301 (INN). If a four-pin shunt is used, the inputs of the AMC3301 are connected to the inner leads and HGND is connected to one of the outer shunt leads. To minimize offset and improve accuracy, set the ground connection to a separate trace that connects directly to the shunt resistor rather than shorting HGND to INN directly at the input to the device. See the *Layout* section for more details.

#### 7.2.2.1 Shunt Resistor Sizing

Use Ohm's Law to calculate the voltage drop across the shunt resistor (V<sub>SHUNT</sub>) for the desired measured current:  $V_{SHUNT} = I \times R_{SHUNT}$ .

Consider the following two restrictions to choose the proper value of the shunt resistor, R<sub>SHUNT</sub>:

- The voltage drop caused by the nominal current range must not exceed the recommended differential input voltage range:  $|V_{SHUNT}| \leq |V_{FSR}|$
- The voltage drop caused by the maximum allowed overcurrent must not exceed the input voltage that causes a clipping output:  $|V_{SHUNT}| \leq |V_{Clipping}|$

#### 7.2.2.2 Input Filter Design

TI recommends placing an RC filter in front of the isolated amplifier to improve signal-to-noise performance of the signal path. Design the input filter such that:

- The cutoff frequency of the filter is at least one order of magnitude lower than the sampling frequency (20 MHz) of the  $\Delta \Sigma$  modulator
- The input bias current does not generate significant voltage drop across the DC impedance of the input filter
- The impedances measured from the analog inputs are equal

For most applications, the structure shown in \begin{aligned} \begin{aligned} \begin{aligned} 7-2 \text{ achieves excellent performance.} \end{aligned}

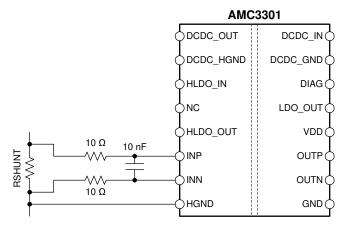


图 7-2. Differential Input Filter

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25

#### 7.2.2.3 Differential to Single-Ended Output Conversion

 $\boxed{8}$  7-3 shows an example of a TLV6001 based signal conversion and filter circuit for systems using single-ended-input ADCs to convert the analog output voltage into digital. With R1 = R2 = R3 = R4, the output voltage equals ( $V_{OUTP} - V_{OUTN}$ ) +  $V_{REF}$ . Tailor the bandwidth of this filter stage to the bandwidth requirement of the system. For most applications, R1 = R2 = R3 = R4 = 3.3 k $\Omega$  and C1 = C2 = 330 pF yields good performance.

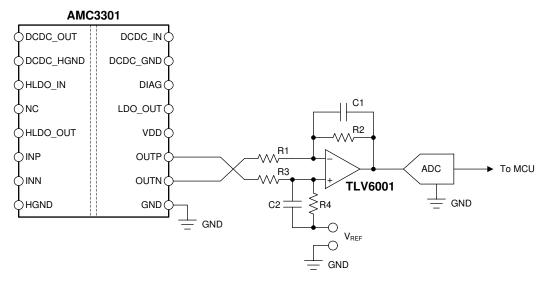


图 7-3. Connecting the AMC3301 Output to a Single-Ended Input ADC

For more information on the general procedure to design the filtering and driving stages of successive-approximation-register (SAR) ADCs, see the 18-Bit, 1MSPS Data Acquisition Block (DAQ) Optimized for Lowest Distortion and Noise reference guide and 18-Bit Data Acquisition Block (DAQ) Optimized for Lowest Power reference guide, available for download at www.ti.com.

### 7.2.3 Application Curve

In frequency inverter applications, the power switches must be protected in case of an overcurrent condition. To allow for fast powering off of the system, a low delay caused by the isolated amplifier is required. 

7-4 shows the typical full-scale step response of the AMC3301. Consider the delay of the required window comparator and the MCU to calculate the overall response time of the system.

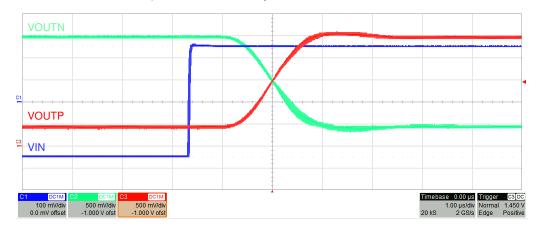


图 7-4. Step Response of the AMC3301

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### 7.3 Best Design Practices

Do not leave the analog inputs INP and INN of the AMC3301 unconnected (floating) when the device is powered up. If the device inputs are left floating, the input bias current may drive the inputs to a positive value that exceeds the operating common-mode input voltage and the output of the device is undetermined.

Connect the negative input (INN) to the high-side ground (HGND), either by a hard short or through a resistive path. A DC current path between INN and HGND is required to define the input common-mode voltage. Take care not to exceed the input common-mode range as specified in the Recommended Operating Conditions table. For best accuracy, route the ground connection as a separate trace that connects directly to the shunt resistor rather than shorting AGND to INN directly at the input to the device. See the Layout section for more details.

The high-side LDO can source a limited amount of current (I<sub>H</sub>) to power external circuitry. Take care not to overload the high-side LDO.

The low-side LDO does not output a constant voltage and is not intended for powering any external circuitry. Do not connect any external load to the LDO OUT pin.

### 7.4 Power Supply Recommendations

The AMC3301 is powered from the low-side power supply (VDD) with a nominal value of 3.3 V or 5 V. TI recommends a low-ESR decoupling capacitor of 1 nF (C8 in \( \brace{8} \) 7-5) placed as close as possible to the VDD pin, followed by a 1-µF capacitor (C9) to filter this power-supply path.

The low-side of the DC/DC converter is decoupled with a low-ESR 100-nF capacitor (C4) positioned close to the device between the DCDC IN and DCDC GND pins. Use a 1-µF capacitor (C2) to decouple the high side in addition to a low-ESR, 1-nF capacitor (C3) placed as close as possible to the device and connected to the DCDC OUT and DCDC HGND pins.

For the high-side LDO, use low-ESR capacitors of 1 nF (C6), placed as close as possible to the AMC3301, followed by a 100-nF decoupling capacitor (C5).

The ground reference for the high-side (HGND) is derived from the terminal of the shunt resistor which is connected to the negative input (INN) of the device. For best DC accuracy, use a separate trace to make this connection instead of shorting HGND to INN directly at the device input. The high-side DC/DC ground terminal (DCDC HGND) is shorted to HGND directly at the device pins.

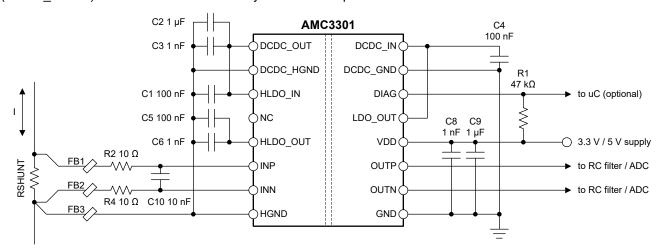


图 7-5. Decoupling the AMC3301

Capacitors must provide adequate effective capacitance under the applicable DC bias conditions they experience in the application. Multilayer ceramic capacitors (MLCC) typically exhibit only a fraction of their nominal capacitance under real-world conditions and this factor must be taken into consideration when selecting

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27



these capacitors. This problem is especially acute in low-profile capacitors, in which the dielectric field strength is higher than in taller components. Reputable capacitor manufacturers provide capacitance versus DC bias curves that greatly simplify component selection.

The Best Practices to Attenuate AMC3301 Family Radiated Emissions EMI application note is available for download at www.ti.com.

表 7-2 lists components suitable for use with the AMC3301. This list is not exhaustive. Other components may exist that are equally suitable (or better), however these listed components have been validated during the development of the AMC3301.

表 7-2. Recommended External Components

	A. I. Rosenmonaed External components									
	DESCRIPTION	PART NUMBER	MANUFACTURER	SIZE (EIA, L x W)						
VDD										
C8	1 nF ± 10%, X7R, 50 V	12065C102KAT2A	AVX	1206, 3.2 mm x 1.6 mm						
C9	1 μF ± 10%, X7R, 25 V	12063C105KAT2A	AVX	1206, 3.2 mm x 1.6 mm						
DC/DC C	ONVERTER									
C4	100 nF ± 10%, X7R, 50 V	C0603C104K5RACAUTO	Kemet	0603, 1.6 mm x 0.8 mm						
C3	1 nF ± 10%, X7R, 50 V	C0603C102K5RACTU	Kemet	0603, 1.6 mm x 0.8 mm						
C2	1 μF ± 10%, X7R, 25 V	CGA3E1X7R1E105K080AC	TDK	0603, 1.6 mm x 0.8 mm						
HLDO										
C1	100 nF ± 10%, X7R, 50 V	C0603C104K5RACAUTO	Kemet	0603, 1.6 mm x 0.8 mm						
C5	100 nF ± 5%, NP0, 50 V	C3216NP01H104J160AA	TDK	1206, 3.2 mm x 1.6 mm						
C6	1 nF ± 10%, X7R, 50 V	12065C102KAT2A	AVX	1206, 3.2 mm x 1.6 mm						
FERRITE	BEADS									
FB1,		74269244182	Wurth Elektronik	0402, 1.0mm × 0.5mm						
FB2,	Ferrite bead <sup>(1)</sup>	BLM15HD182SH1	Murata	0402, 1.0mm × 0.5mm						
FB3		BKH1005LM182-T	Taiyo Yuden	0402, 1.0mm × 0.5mm						

<sup>(1)</sup> No ferrite beads are used for parametric validation.

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#### 7.5 Layout

#### 7.5.1 Layout Guidelines

🗵 7-6 shows a layout recommendation with the critical placement of the decoupling capacitors. The same component reference designators are used as in the Power Supply Recommendations section. Decoupling capacitors are placed as close as possible to the AMC3301 supply pins. For best performance, place the shunt resistor close to the INP and INN inputs of the AMC3301 and keep the layout of both connections symmetrical.

To avoid causing errors in the measurement by the input bias currents of the AMC3301, connect the high-side ground pin (HGND) to the INN-side of the shunt resistor. Use a separate trace in the layout to make this connection to maintain equal currents in the INN and INP traces.

### 7.5.2 Layout Example

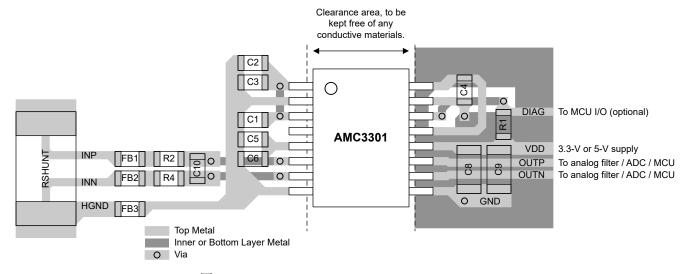


图 7-6. Recommended Layout of the AMC3301

Product Folder Links: AMC3301

29



### 8 Device and Documentation Support

### 8.1 Device Support

#### 8.1.1 Device Nomenclature

Texas Instruments, Isolation Glossary

### 8.2 Documentation Support

#### 8.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, ISO72x Digital Isolator Magnetic-Field Immunity application report
- Texas Instruments, AMC3330 Precision, ±1-V Input, Reinforced Isolated Amplifier data sheet
- Texas Instruments, TLV600x Low-Power, Rail-to-Rail In/Out, 1-MHz Operational Amplifier for Cost-Sensitive Systems data sheet
- Texas Instruments, 18-Bit, 1-MSPS Data Acquisition Block (DAQ) Optimized for Lowest Distortion and Noise reference guide
- Texas Instruments, 18-Bit, 1-MSPS Data Acquisition Block (DAQ) Optimized for Lowest Power reference guide

### 8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.4 支持资源

TI E2E™中文支持论坛是工程师的重要参考资料,可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题,获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的使用条款。

#### 8.5 Trademarks

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#### 8.6 静申放申警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

#### 8.7 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

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# **9 Revision History**

注:以前版本的页码可能与当前版本的页码不同

С	hanges from Revision B (May 2021) to Revision C (May 2025)	Page
•	通篇将增强型隔离安全相关认证从 VDE V 0884-11 更改为 DIN EN IEC 60747-17 (VDE 0884-17)	1
•	Added analog output capacitive and resistive drive capability specification	4
•	Added DIGITAL OUTPUT (DIAG) specification	4
•	Updated Barrier capacitance specification from 3.5 pF to 4.5 pF	6
•	Changed isolation standard from DIN VDE V 0884-11 (VDE V 0884-11) to DIN EN IEC 60747-17 (VDE	
	0884-17) and updated the Insulation Specifications and Safety-Related Certifications tables accordingly	
•	Added DIGITAL OUTPUT (DIAG) electrical specifications	8
•	Added VDD <sub>UV</sub> and VDD <sub>POR</sub> specifications	
•	Added IH specification for 3.6 V $\leq$ VDD $\leq$ 5.5 V	
•	Changed HLDO_OUT pin to LDO_OUT pin in Best Design Practices section	27
С	hanges from Revision A (July 2020) to Revision B (May 2021)	Page
•	更改了"特性"部分:更改了 <i>低直流误差</i> 要点中的 <i>失调电压和温漂</i> 子要点,重新排列了各要点,添加了	
	一个要点	
•	将 <i>应用</i> 部分的目标应用从 <i>隔离式电压检测</i> 更改为 <i>基于分流器的隔离式电流检测</i>	
•	Changed Pin Configuration and Functions section	
•	Changed Absolute Maximum Ratings: changed max for DIAG pin from 5.5 V to 6.5 V	
•	Changed overvoltage category for rated mains voltage ≤ 600 V from I-IV to I-III and for rated mains vo	•
	≤1000 V from I-III to I-II	
•	Changed output bandwidth (BW) (min) from 250 kHz to 290 kHz	
•	Changed Typical Characteristics section. Removed histograms, editorial changes	
•	Changed Functional Block Diagram figure	
•	Changed Data Isolation Channel Signal Transmission section	
•	Changed Analog Output section	
•	Changed Diagnostic Output section: added DIAG Output Under Different Operating Conditions figure	
•	Changed Typical Application section	
•	Changed Input Filter Design section: changed Differential Input Filter figure	
•	Added Differential to Single-Ended Output Conversion section	
•	Changed Step Response of the AMC3301 figure	
•	Changed Power Supply Recommendations section: changed nominal value in the first sentence from 3 $(or 5 V) \pm 10 V$ to 3.3 $V$ or 5 $V$ , changed primary-side to low-side, secondary-side to high-side, and	≀.3 V
	Decoupling the AMC3301 figure	27
•	Changed Recommended Layout of the AMC3301 figure	
	• • • • • • • • • • • • • • • • • • •	

# 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: AMC3301

www.ti.com 7-Nov-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
AMC3301DWE	Active	Production	SOIC (DWE)   16	40   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWE.A	Active	Production	SOIC (DWE)   16	40   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWE.B	Active	Production	SOIC (DWE)   16	40   TUBE	-	Call TI	Call TI	-40 to 125	
AMC3301DWEG4	Active	Production	SOIC (DWE)   16	40   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWEG4.A	Active	Production	SOIC (DWE)   16	40   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWEG4.B	Active	Production	SOIC (DWE)   16	40   TUBE	-	Call TI	Call TI	-40 to 125	
AMC3301DWER	Active	Production	SOIC (DWE)   16	2000   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWER.A	Active	Production	SOIC (DWE)   16	2000   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	AMC3301
AMC3301DWER.B	Active	Production	SOIC (DWE)   16	2000   LARGE T&R	-	Call TI	Call TI	-40 to 125	

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# PACKAGE OPTION ADDENDUM

www.ti.com 7-Nov-2025

and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF AMC3301:

Automotive : AMC3301-Q1

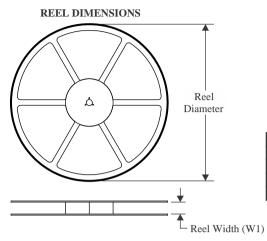
NOTE: Qualified Version Definitions:

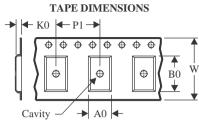
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 18-Jul-2025

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

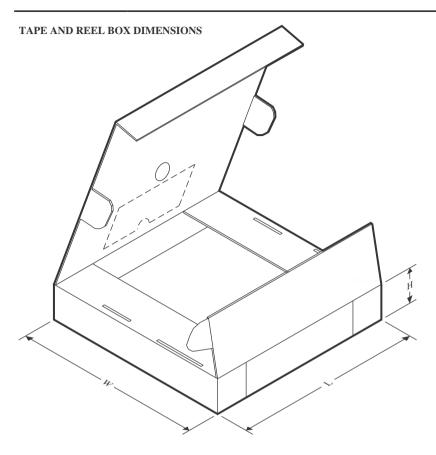


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AMC3301DWER	SOIC	DWE	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 18-Jul-2025



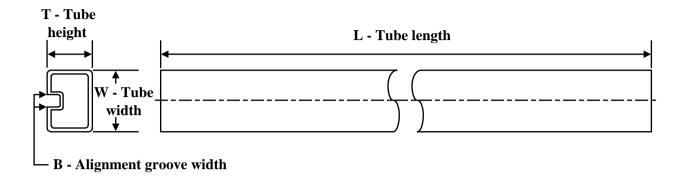
### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
AMC3301DWER	SOIC	DWE	16	2000	350.0	350.0	43.0	

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 18-Jul-2025

### **TUBE**

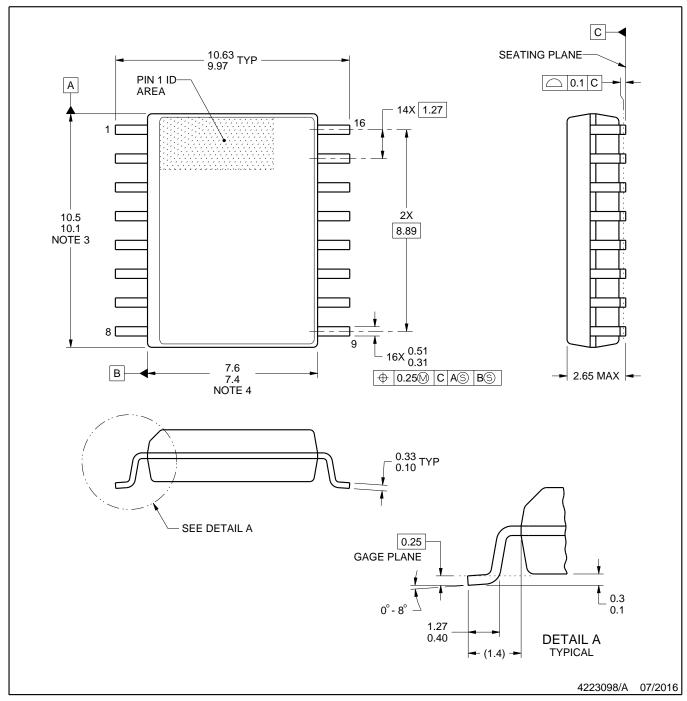


#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
AMC3301DWE	DWE	SO-MOD	16	40	506.98	12.7	4826	6.6
AMC3301DWE.A	DWE	SO-MOD	16	40	506.98	12.7	4826	6.6
AMC3301DWEG4	DWE	SO-MOD	16	40	506.98	12.7	4826	6.6
AMC3301DWEG4.A	DWE	SO-MOD	16	40	506.98	12.7	4826	6.6



SOIC



#### NOTES:

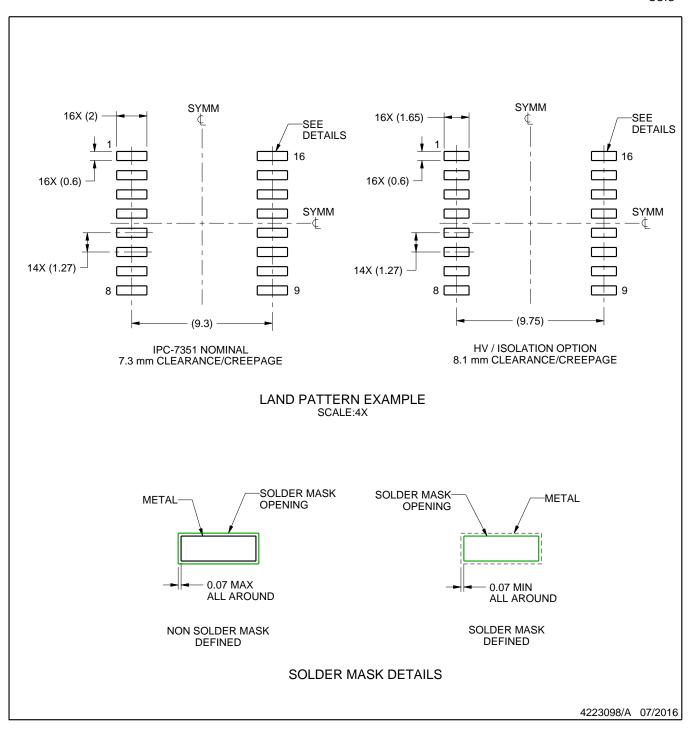
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



SOIC



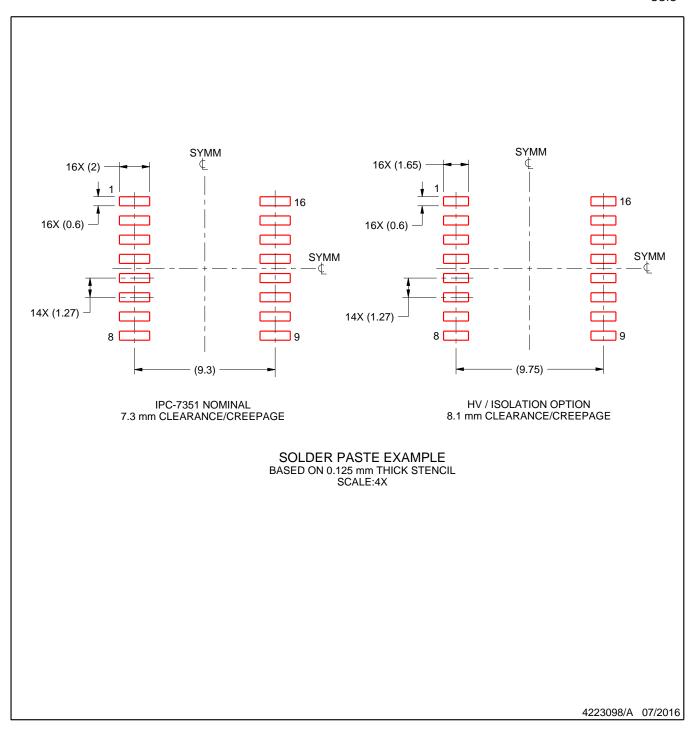
#### NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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